

Reflective Object Sensor

OPB703 through OPB705,
OPB703WZ through OPB705WZ,
OPB70AWZ through OPB70HWZ



Features:

- Phototransistor output
- High sensitivity
- Low-cost plastic housing
- Available with lenses for dust protection and ambient light filtration
- Focused for maximum sensitivity

Description:

The **OPB703**, **OPB704** and **OPB705** consist of an Infrared (890nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for PCBoard mounting. The **OPB703WZ**, **OPB704WZ**, **OPB705WZ** and **OPB70BWZ** are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

The **OPB70AWZ** consists of an Infrared (890nm) Light Emitting Diode (LED) and a NPN silicon Photodarlington, mounted side-by-side on converging optical axes in a black plastic housing and is designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

The **OPB70CWZ through OPB70FWZ** consist of a Visible (Red 640nm) Light Emitting Diode (LED) and a NPN silicon Phototransistor or Rbe Phototransistor, mounted side-by-side on converging optical axes in a black plastic housing and are designed for remote mounting utilizing interconnect wires of UL approved 26 AWG, 24" (61.0cm) minimum length, stripped and tinned.

Various lens options are available: No lens for the (**OPB703**, **OPB703WZ**), blue window for dust protection for the (**OPB704**, **OPB704WZ**, **OPB70BWZ**, **OPB70HWZ**) and aperture lens for improved resolution for the (**OPB705**, **OPB705WZ**, **OPB70AWZ**, **OPB70CWZ**, **OPB70DWZ**). The **OPB704G** and **OPB704GWZ** offers excellent protection for dirty environments.

The phototransistor responds to illumination from the emitter when a reflective object passes within the field of view centered typically at 0.15" (3.8 mm).

Custom electrical, wire, cabling and connectors are available. Contact your local representative or OPTEK for more information.

Applications:

- Non-contact reflective object sensor
- Assembly line automation
- Machine automation
- Machine safety
- End of travel sensor
- Door sensor
- Mark Detection
- Office Equipment



RoHS

Ordering Information				
Part	LED Peak	Detector	Optical Cover	Lead or Wire
OPB703	890 nm	Transistor	None	0.160" Leads
OPB703WZ				24" / 26 AWG Wire
OPB704			Blue Window	0.160" Leads
OPB704WZ				24" / 26 AWG Wire
OPB70HWZ				24" / 26 AWG Wire
OPB704G				0.160" Leads
OPB704GWZ				24" / 26 AWG Wire
OPB705			Aperture	0.160" Leads
OPB705WZ				24" / 26 AWG Wire
OPB70AWZ				
OPB70BWZ		Darlington	Blue Window	
OPB70CWZ	640 nm	Rbe Transistor	Aperture	24" / 26 AWG Wire
OPB70DWZ		Transistor		
OPB70EWZ		Rbe Transistor	Clear Window	
OPB70FWZ		Transistor		

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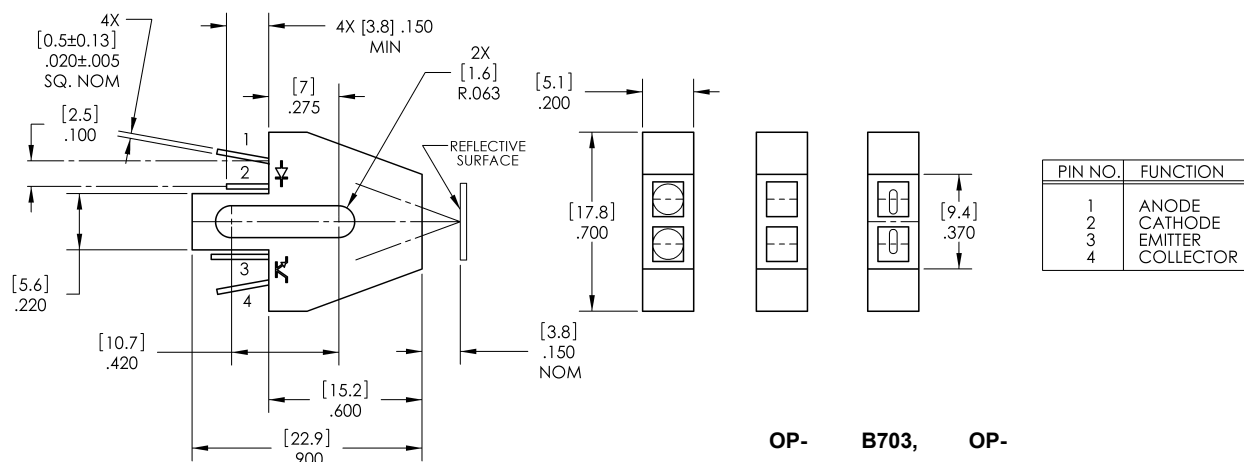
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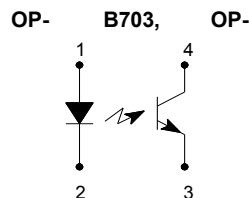
OPB703 through OPB705,
OPB703WZ through OPB705WZ,
OPB70AWZ through OPB70HWZ



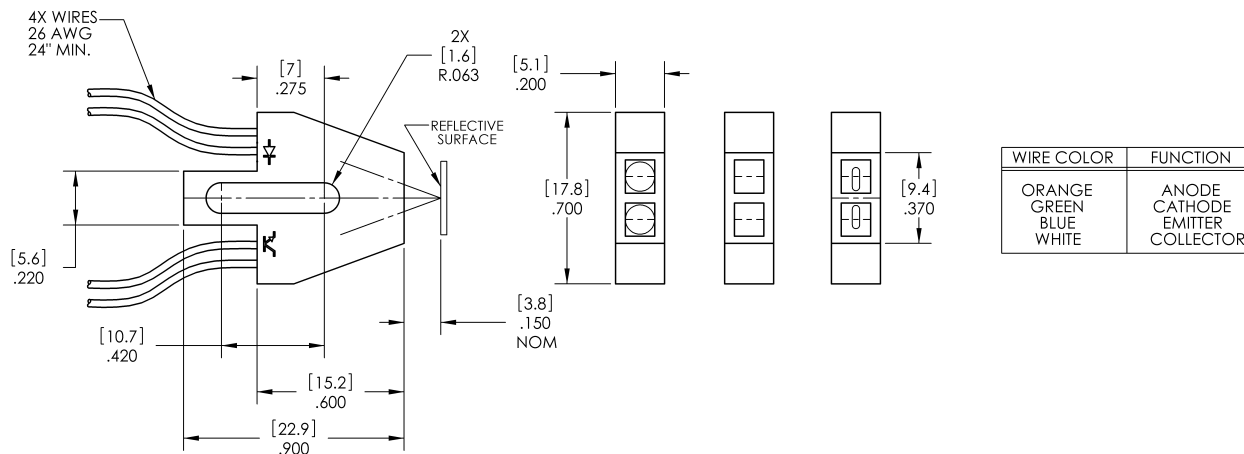
OPB703, OPB704, OPB705



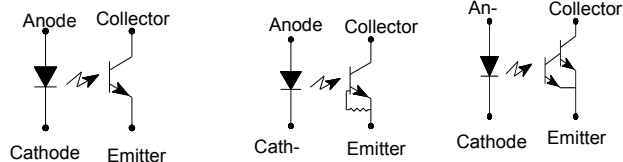
DIMENSIONS ARE IN INCHES [MM]
TOLERANCES ARE $\pm .010$ UNLESS OTHERWISE SPECIFIED.



OPB703WZ, OPB704WZ, OPB705WZ, OPB70AWZ, OPB70BWZ, OPB70CWZ, OPB70DWZ



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Absolute Maximum Ratings ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

Storage Temperature Range	-40°C to +80° C
Lead Soldering Temperature [1/16 inch (1.6 mm) from the case for 5 sec. with soldering iron]	240° C ⁽¹⁾
Input Diode	
Forward DC Current	40 mA
Reverse DC Voltage	2 V
Power Dissipation	100 mW ⁽²⁾
Output Photodetector	
Collector-Emitter Voltage	30 V 15 V
Phototransistor	
Photodarlington	
Emitter-Collector Voltage	5 V
Collector DC Current	25 mA
Power Dissipation	100 mW ⁽²⁾

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703WZ, OPB704WZ, OPB705WZ, OPB70BWZ, OPB704G, OPB704GWZ and OPB70HWZ derate linearly 1.82 mW/° C above 25° C.

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OPB70AWZ through OPB70HWZ



Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

(OPB703, OPB703WZ, OPB704, OPB704WZ, OPB705, OPB705WZ, OPB704G, OPB704GWZ, OPB70HWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode (See OP265 for additional information — for reference only)						
V_F	Forward Voltage	-	-	1.7	V	$I_F = 40\text{mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2\text{V}$
Output Phototransistor (See OP505 for additional information — for reference only)						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100\text{ }\mu\text{A}$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_{EC} = 100\text{ }\mu\text{A}$
I_{CEO}	Collector Dark Current	-	-	250	nA	$V_{CE} = 10\text{V}, I_F = 0, E_E = 0$
Coupled						
$I_{C(ON)}$	On-State Collector Current OPB70HWZ	0.60	-	3.5	mA	$V_{CE} = 5\text{V}, I_F = 40\text{mA}, d = 0.15''^{(4)(6)}$
	OPB703, OPB703WZ	0.30	-	2.5		
	OPB704, OPB704WZ	0.20	-	2.5		
	OPB704G, OPB704GWZ	0.50	-	6.0		$V_{CE} = 5\text{V}, I_F = 40\text{mA}, d = 0.20''^{(4)(6)}$
I_{CX}	Crosstalk OPB703, OPB703WZ	-	-	20	μA	$V_{CE} = 5\text{V}, I_F = 40\text{mA}^{(5)}$
	OPB704, OPB704WZ, OPB70HWZ	-	-	20		

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) For OPB703, OPB704 and OPB705, derate linearly 1.67 mW/ $^\circ\text{C}$ above 25°C .
- (3) For OPB703WZ, OPB704WZ, OPB705WZ, OPB70BWZ, OPB704G, OPB704GWZ, OPB70HWZ, OPB70AWZ, OPB70CWZ, OPB70DWZ, OPB70EWZ, and OPB70FWZ derate linearly 1.82 mW/ $^\circ\text{C}$ above 25°C .
- (4) The distance from the assembly face to the reflective surface is d.
- (5) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (6) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.
- (7) All parameters tested using pulse techniques.

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OPB703WZ through OPB705WZ,
OPB70AWZ through OPB70HWZ



Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted) (OPB70AWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode (See OP265 for additional information — for reference only)						
V_F	Forward Voltage	-	-	1.7	V	$I_F = 40\text{mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2\text{V}$
Output PhotoDarlington (See OP535 for additional information — for reference only)						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	15	-	-	V	$I_{CE} = 1.0\text{mA}$, $E_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5	-	-	V	$I_{EC} = 100\mu\text{A}$, $E_E = 0$
I_{CEO}	Collector Dark Current	-	-	250	nA	$V_{CE} = 10\text{V}$, $I_F = 0$, $E_E = 0$
Coupled						
$I_{C(ON)}$	On-State Collector Current	5.0	-	26.0	mA	$V_{CE} = 5\text{V}$, $I_F = 40\text{mA}$, $d = 0.15''$ ⁽¹⁾⁽³⁾
$V_{(SAT)}$	Saturation Voltage	-	-	1.15	V	$I_C = 400\mu\text{A}$, $I_F = 40\text{mA}$, $d = 0.15''$ ⁽¹⁾⁽³⁾
I_{CX}	Crosstalk	-	-	25	μA	$V_{CE} = 5\text{V}$, $I_F = 40\text{mA}$ ⁽²⁾

Notes:

- (1) The distance from the assembly face to the reflective surface is d .
- (2) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (3) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

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OPB703WZ through OPB705WZ,
OPB70AWZ through OPB70HWZ



Electrical Characteristics ($T_A = 25^\circ \text{C}$ unless otherwise noted) (OPB70BWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode (See OP265 for additional information — for reference only)						
V_F	Forward Voltage	-	-	1.7	V	$I_F = 40\text{mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2 \text{ V}$
Output Phototransistor (See OP705 for additional information — for reference only)						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100 \mu\text{A}$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	0.4	-	-	V	$I_{EC} = 100\mu\text{A}$
I_{CEO}	Collector Dark Current	-	-	100	nA	$V_{CE} = 10 \text{ V}, I_F = 0, E_E = 0$
Coupled						
$I_{C(ON)}$	On-State Collector Current OPB70BWZ	0.50	-	3.0	mA	$V_{CE} = 5 \text{ V}, I_F = 40\text{mA}, d = 0.15''^{(1)(3)}$
I_{CX}	Crosstalk OPB70BWZ	-	-	5	μA	$V_{CE} = 5 \text{ V}, I_F = 40\text{mA}^{(2)}$

Notes:

- (1) The distance from the assembly face to the reflective surface is d .
- (2) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (3) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

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OPB70AWZ through OPB70HWZ



Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted) (OPB70CWZ and OPB70EWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode (See OVLAS6CB8 for additional information — for reference only)						
V_F	Forward Voltage	-	-	2.6	V	$I_F = 40\text{mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2\text{V}$
Output Phototransistor (See OP505 for additional information — for reference only)						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100\mu\text{A}$, $I_F = 0$, $E_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	0.4	-	-	V	$I_{EC} = 100\mu\text{A}$, $I_F = 0$, $E_E = 0$
I_{CEO}	Collector Dark Current	-	-	100	nA	$V_{CE} = 10\text{V}$, $I_F = 0$, $E_E = 0$

Coupled

I _{C(ON)}	On-State Collector Current	OPB70CWZ	.10	-	1.0	mA	V _{CE} = 5 V, I _F = 40mA , d = 0.15" ⁽²¹⁾⁽³⁾
		OPB70EWZ	.25	-	2.5		
V _(SAT)	Saturation Voltage		-	-	0.4	V	
I _C = 100 μA, I _F = 40mA , d = 0.15" ⁽¹⁾⁽³⁾							
I _{CX}	Crosstalk		-	-	2	μA	V _{CE} = 5 V, I _F = 40mA ⁽²⁾

Notes:

- (1) The distance from the assembly face to the reflective surface is d .
- (2) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (3) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

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OPB703WZ through OPB705WZ,
OPB70AWZ through OPB70HWZ



Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted) (OPB70DWZ and OPB70FWZ)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode (See OVLAS6CB8 for additional information — for reference only)						
V_F	Forward Voltage	-	-	2.6	V	$I_F = 40\text{mA}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2\text{V}$
Output Phototransistor (See OP505 for additional information — for reference only)						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	30	-	-	V	$I_{CE} = 100\mu\text{A}$, $I_F = 0$, $E_E = 0$
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage	5.0	-	-	V	$I_{EC} = 100\mu\text{A}$, $I_F = 0$, $E_E = 0$
I_{CEO}	Collector Dark Current	-	-	250	nA	$V_{CE} = 10\text{V}$, $I_F = 0$, $E_E = 0$

Coupled

I _{C(ON)}	On-State Collector Cur- rent	OPB70DWZ	.10	-	1.5	mA	V _{CE} = 5 V, I _F = 40mA , d = 0.15" ⁽¹⁾⁽³⁾	
		OPB70FWZ	.25	-	3.5			
V _(SAT)	Saturation Voltage		-	-	0.4	V		I _{C(ON)} = 100 μA, I _F = 40mA , d = 0.15" ⁽¹⁾⁽³⁾
I _{CX}	Crosstalk		-	-	5.0	μA		V _{CE} = 5 V, I _F = 40mA ⁽²⁾

Notes:

- (1) The distance from the assembly face to the reflective surface is d .
- (2) Crosstalk (I_{CX}) is the collector current measured with the indicated current in the input diode and with no reflecting surface.
- (3) Measured using Eastman Kodak neutral white test card with 90% diffuse reflectance as a reflecting surface. Reference: Eastman Kodak, Catalog # E 152 7795.

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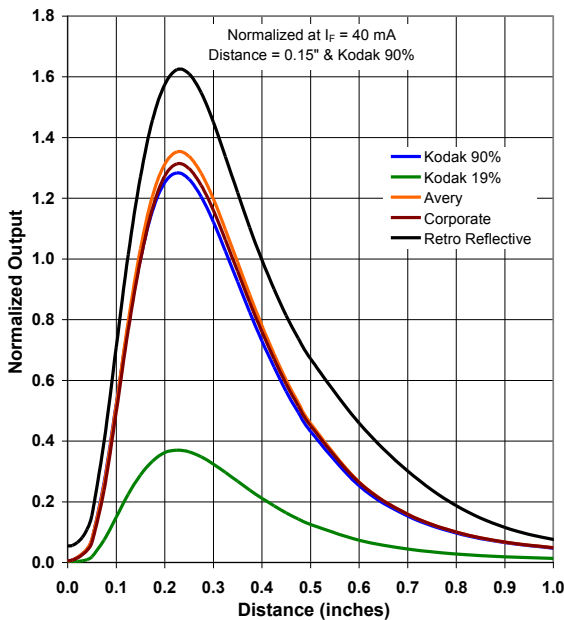
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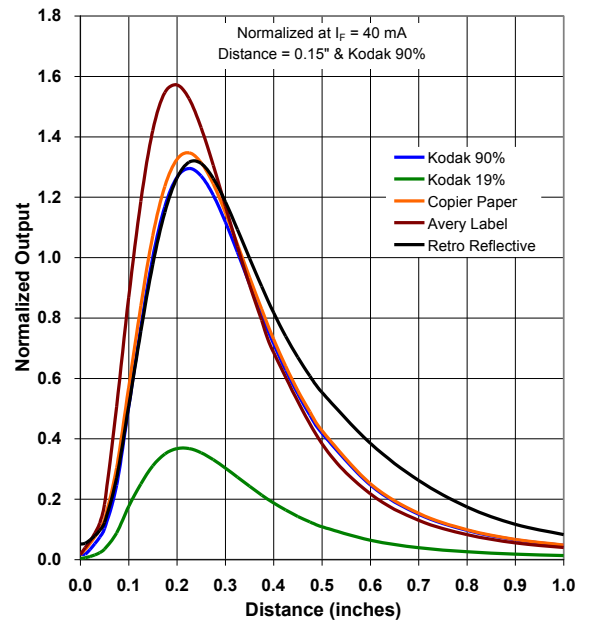
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OPB703WZ through OPB705WZ,
OPB70AWZ through OPB70HWZ



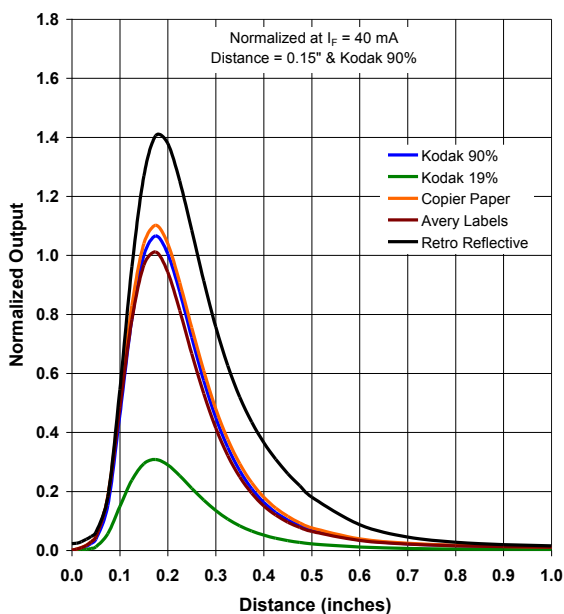
OPB703 - Output vs Distance



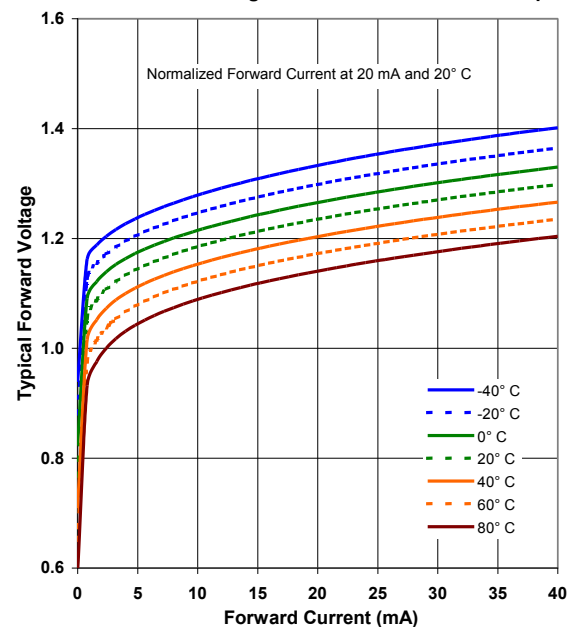
OPB704 - Output vs Distance



OPB705 - Output vs Distance



Forward Voltage vs Forward Current vs Temp



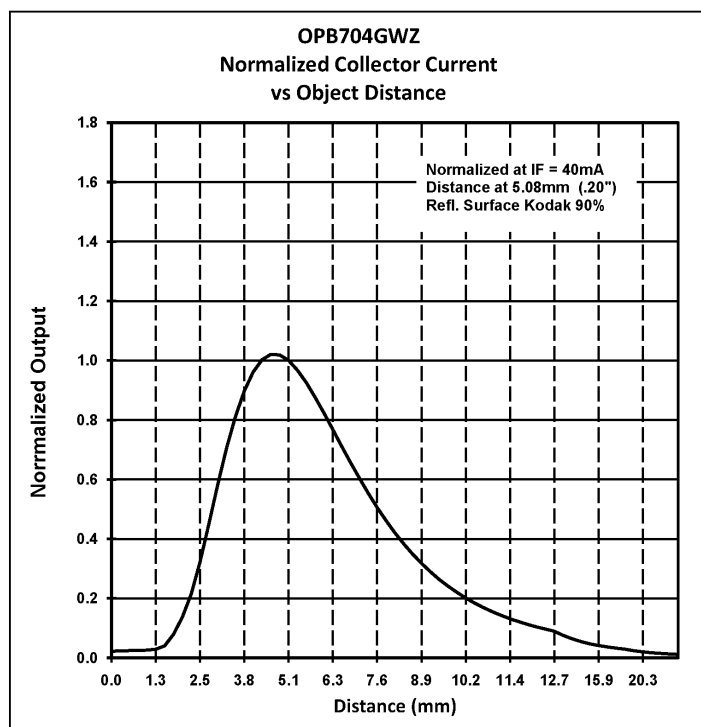
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